HALOGEN FREE

GREEN



Vishay Semiconductors

DH Backlighting LED in Ø 3 mm Tinted Non-Diffused Package



DESCRIPTION

The TLVD4200 serie was developed for backlighting in the extrem bright double heterojunction (DH) red GaAlAs on GaAs technology. Due to its special shape the spatial distribution of the radiation is qualified for backlighting.

To optimize the brightness of backlighting a custom-built reflector (with scattering) is required. Uniform illumination can be enhanced by covering the front of the reflector with diffusor material.

This is a bright and flexible solution for backlighting different areas.

PRODUCT GROUP AND PACKAGE DATA

• Product group: LED

Package: 3 mm backlighting
Product series: standard
Angle of half intensity: ± 85°

FEATURES

- · High brightness
- · Wide viewing angle
- Categorized for luminous flux
- · Available in DH red
- Tinted clear package
- · Low power dissipation
- · Low self heating
- Rugged design
- High reliability
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

APPLICATIONS

- Backlighting of display panels, LCD displays, symbols on switches, keyboards, graphic boards, and measuring scales
- Illumination of large areas e.g. dot matrix displays

PARTS TABLE														
PART	ART COLOR		LUMINOUS FLUX (mlm)		at I _F (mA)		VELENGTH (nm)		at I _F	FORWARD VOLTAGE (V)		at I _F (mA)	TECHNOLOGY	
		MIN.	TYP.	MAX.	(IIIA)	MIN.	TYP.	MAX.	(IIIA)	MIN.	TYP.	MAX.	(IIIA)	
TLVD4200	Red	40	130	-	15	-	640	-	10	1	1.8	2.2	20	GaAlAs on GaAs
TLVD4200-MSZ	Red	40	130	-	15	-	640	-	10	-	1.8	2.2	20	GaAlAs on GaAs

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) TLVD4200						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Reverse voltage		V _R	6	V		
DC forward current		I _F	50	mA		
Surge forward current	t _p ≤ 10µs	I _{FSM}	1	Α		
Power dissipation	T _{amb} ≤ 60 °C	P _V	100	mW		
Junction temperature		Tj	100	°C		
Operating temperature range		T _{amb}	-40 to +100	°C		
Storage temperature range		T _{stg}	-55 to +100	°C		
Soldering temperature	t ≤ 5 s, 2 mm from body	T _{sd}	260	°C		
Thermal resistance junction/ambient		R _{thJA}	400	K/W		

Vishay Semiconductors

OPTICAL AND ELECTRICAL CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified) TLVD4200, RED						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous flux	I _F = 15 mA	φ _V	40	130	-	mlm
Dominant wavelength	I _F = 10 mA	λ_{d}	-	640	-	nm
Peak wavelength	I _F = 10 mA	λρ	-	650	-	nm
Angle of half intensity	I _F = 10 mA	φ	-	± 85	-	deg
Forward voltage	I _F = 20 mA	V _F	-	1.8	2.2	V
Reverse voltage	I _R = 10 μA	V _R	6	15	-	V
Junction capacitance	V _R = 0 V, f = 1 MHz	C _j	=	50	-	pF

LUMINOUS FLUX CLASSIFICATION						
GROUP	LUMINOU	S FLUX (mlm)				
STANDARD	MIN.	MAX.				
U	40	80				
V	63	125				
W	100	200				
X	130	260				
Y	180	360				
Z	240	480				

Note

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each bag (there will be no mixing of two groups in each bag).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one bag. In order to ensure availability, single wavelength groups will not be orderable.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

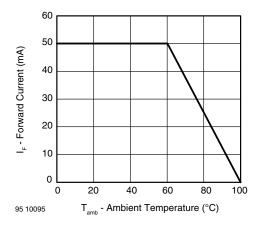


Fig. 1 - Forward Current vs. Ambient Temperature

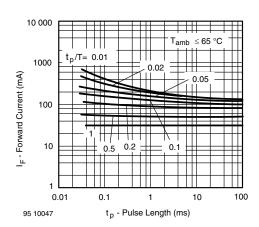


Fig. 2 - Forward Current vs. Pulse Length

Luminous flux is tested at a current pulse duration of 25 ms.

Vishay Semiconductors



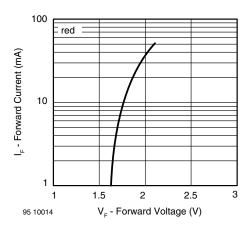


Fig. 3 - Forward Current vs. Forward Voltage

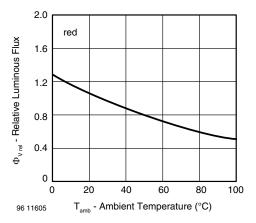


Fig. 4 - Relative Luminous Flux vs. Ambient Temperature

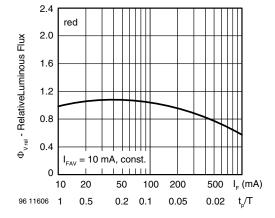


Fig. 5 - Relative Luminous Flux vs. Forward Current / Duty Cycle

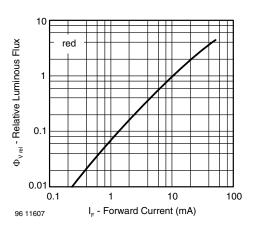


Fig. 6 - Relative Luminous Flux vs. Forward Current

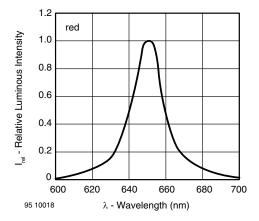


Fig. 7 - Relative Intensity vs. Wavelength

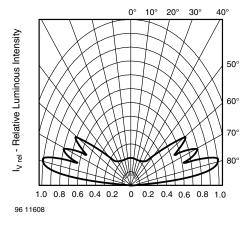
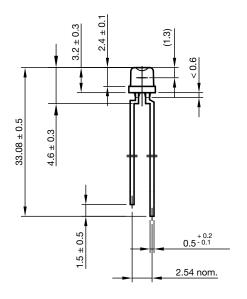


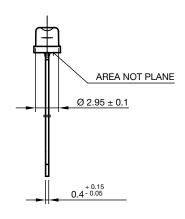
Fig. 8 - Relative Luminous Intensity vs. Angular Displacement for 90 ° Emission Angle



PACKAGE DIMENSIONS in millimeters









Drawing-No.: 6.544-5226.01-4

Issue: 2; 28.07.14

AMMOPACK

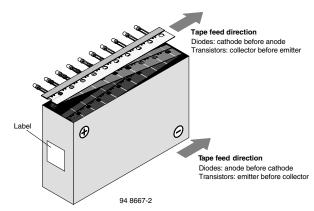


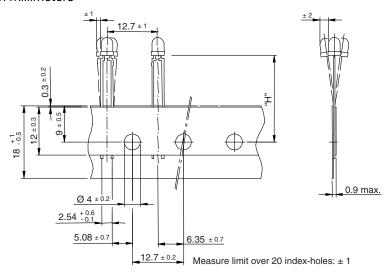
Fig. 9 - Tape Direction

Note

 The new nomenclature for ammopack is e.g. ASZ only, without suffix for the LED orientation. The carton box has to be turned to the desired position: "+" for anode first, or "-" for cathode first. AS12Z and AS21Z are still valid for already existing types, BUT NOT FOR NEW DESIGN.

Vishay Semiconductors

TAPE DIMENSIONS in millimeters



	Reel
Quantity per:	(Mat No. 1764)
	2000

94 8171

Option	Dim. "H" ± 0.5 mm		
MS	25.5		



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.